

1. Number	Hits	Search Text	LS	Time Stamp
1	0	'EPROM' and @ad<=20010504 and 'trapping layer' and 'TiO.sub.2'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
2	31	'EPROM' and @ad<=20010504 and 'trapping layer'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
3	214	'EPROM' and @ad<=20010504 and 'high dielectric'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
4	1	'EPROM' and @ad<=20010504 and 'high dielectric' and 'charge adj. time'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
6	6	(257/316).cccls. and @ad<=20010504 and 'high k'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
7	9	(257/316).cccls. and @ad<=20010504 and 'high k'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
8	5	(257/314).cccls. and @ad<=20010504 and 'high k'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	2521	((257/310) or (257/306) or (257/315)).CCCLS.	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	2439	((257/310) or (257/306) or (257/315)).CCCLS. and @ad<=20010504	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	428	((257/310) or (257/306) or (257/315)).CCCLS. and @ad<=20010504 and 'high dielectric'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	247	((257/310) or (257/306) or (257/315)).CCCLS. and @ad<=20010504 and 'high dielectric' and 'charge adj. time'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	412	(257/314).CCCLS.	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	421	(257/314).CCCLS. and @ad<=20010504	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44
-	14	(257/314).CCCLS. and @ad<=20010504 and 'high dielectric'	USPAT; US-PGPUB; EPC; JPC; DERWENT; IBM_TIP	2002/11/11 16:44

-	334	((257/310) or (257/310) or 257/310) .CCLS. and Badk=20010504 and 'Flash memory'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	6977	257/310-331 .CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	61	257/310-331 .CCLS. and Badk=20010504 and 'high dielectric' and 'flash memory'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	1	41890.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	3	("4464701") .PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	2	("6307731") .PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	6	109261.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	129125	(257/\$) .CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	9036	257/\$ .CCLS. and 'FET'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	303	((257/\$) .CCLS.) and 'FET' and 'high dielectric'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	18	((257/\$) .CCLS.) and 'FET' and 'high dielectric' and 'stacked structure'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	14	257/\$ .CCLS. and 'FET' and 'high dielectric' and 'stacked structure' and Badk=20010504	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	141	257/\$ .CCLS. and 'FET' and 'titanium'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504
-	9036	257/\$ .CCLS. and 'FET'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TIB	20010504





